NSN 5961-01-306-5471

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-306-5471

Inclosure Material:

Metal

Overall Length:

1.218 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

0.438 inches

Thread Size:

0.190 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

120.0 collector to base voltage/static/emitter open and 80.0 collector to emitter voltage/static/base open and 7.0 emitter to base voltage,

static, collector open

Current Rating Per Characteristic:

20.00 amperes source cutoff current

Power Rating Per Characteristic:

30.0 watts small-signal input power, common-collector preset

Transfer Ratio:

50.0 static forward current transfer ratio, common-emitter and 250.0 static forward current transfer ratio, common-emitter

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

Special Features:

Junction pattern arrangement: npn

Thread Series Designator:

Unf

Terminal Type And Quantity:

3 tab, solder lug and 1 case

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0